



RELIABILITY REPORT
FOR
MAX9653AUB+
PLASTIC ENCAPSULATED DEVICES

June 3, 2010

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.
SUNNYVALE, CA 94086

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| Approved by |
| Don Lipps |
| Quality Assurance |
| Manager, Reliability Engineering |

Conclusion

The MAX9653AUB+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX9652/MAX9653/MAX9654 are 3.3V, triple-channel, high-definition (HD) video-filter amplifiers. Specially designed for YPbPr component video signals, these devices are ideal for a wide range of set-top box and portable applications. The inputs to the MAX9652/MAX9653/MAX9654 are AC-coupled. YIN has a sync-tip clamp while PBIN and PRIN have keyed clamps. The output buffer has gain of 2V/V and drives a standard back-terminated 75 video load. The passband of the MAX9654 is logic selectable between standard definition (SD) and high definition. The MAX9652/MAX9653 have a fixed passband for HD video. The MAX9654 SD lowpass filter has ± 1 dB passband out to 8.5MHz and 57dB attenuation at 27MHz. The MAX9652/MAX9653/MAX9654 HD lowpass filter have ± 1 dB passband out to 42MHz and 50dB attenuation at 109MHz. The devices consume only 9.5mA per channel and operate from a 3.3V supply. The MAX9653/MAX9654 feature a low-power, 12 μ A shutdown mode. The MAX9652/MAX9653/MAX9654 are specified over the -40°C to +125°C automotive temperature range.

II. Manufacturing Information

| | |
|----------------------------------|--|
| A. Description/Function: | 3.3V, HD/SD Triple-Channel Filter Amplifiers with Shutdown |
| B. Process: | S4 |
| C. Number of Device Transistors: | 552 |
| D. Fabrication Location: | California, Texas or Japan |
| E. Assembly Location: | Malaysia, Philippines, Thailand |
| F. Date of Initial Production: | July 25, 2008 |

III. Packaging Information

| | |
|--|--------------------------|
| A. Package Type: | 10-pin uMAX |
| B. Lead Frame: | Copper |
| C. Lead Finish: | 100% matte Tin |
| D. Die Attach: | Conductive |
| E. Bondwire: | Au (1 mil dia.) |
| F. Mold Material: | Epoxy with silica filler |
| G. Assembly Diagram: | #05-9000-3202 |
| H. Flammability Rating: | Class UL94-V0 |
| I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C | Level 1 |
| J. Single Layer Theta Ja: | 180°C/W |
| K. Single Layer Theta Jc: | 41.9°C/W |
| L. Multi Layer Theta Ja: | 113.1°C/W |
| M. Multi Layer Theta Jc: | 41.9°C/W |

IV. Die Information

| | |
|----------------------------|---|
| A. Dimensions: | 54 X 61 mils |
| B. Passivation: | Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide) |
| C. Interconnect: | Al with Ti/TiN Barrier |
| D. Backside Metallization: | None |
| E. Minimum Metal Width: | Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn) |
| F. Minimum Metal Spacing: | Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn) |
| G. Bondpad Dimensions: | 5 mil. Sq. |
| H. Isolation Dielectric: | SiO ₂ |
| I. Die Separation Method: | Wafer Saw |

V. Quality Assurance Information

- A. Quality Assurance Contacts: Don Lipps (Manager, Reliability Engineering)
Bryan Preeshl (Managing Director of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 48 \times 2} \text{ (Chi square value for MTTF upper limit)}$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 22.9 \times 10^{-9}$$

$$\lambda = 22.9 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maxim-ic.com/qa/reliability/monitor>. Cumulative monitor data for the S4 Process results in a FIT Rate of 0.05 @ 25C and 0.83 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The VA70 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA.

Table 1
Reliability Evaluation Test Results

MAX9653AUB+

| TEST ITEM | TEST CONDITION | FAILURE IDENTIFICATION | SAMPLE SIZE | NUMBER OF FAILURES |
|-----------------------------------|---|-------------------------------|-------------|--------------------|
| Static Life Test (Note 1) | | | | |
| | Ta = 135°C Biased Time = 192 hrs. | DC Parameters & functionality | 48 | 0 |
| Moisture Testing (Note 2) | | | | |
| HAST | Ta = 130°C RH = 85% Biased Time = 96hrs. | DC Parameters & functionality | 77 | 0 |
| Mechanical Stress (Note 2) | | | | |
| Temperature Cycle | -65°C/150°C 1000 Cycles Method 1010 | DC Parameters & functionality | 77 | 0 |

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data